# NSN 5961-01-220-8207

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#### **Inclosure Material:**

Metal

# **Overall Length:**

Between 1.553 inches and 1.573 inches

# **Overall Height:**

0.905 inches

# **Overall Width:**

1.050 inches

# **Mounting Facility Quantity:**

2

# Internal Configuration:

Junction contact

# Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-3

# Electrode Internally-electrically Connected To Case:

Collector

#### Mounting Method:

Unthreaded hole

#### Features Provided:

Electrostatic sensitive and hermetically sealed case

#### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

1400.0 collector to base voltage/static/emitter open and 1000.0 collector to emitter voltage/static/base open and 1400.0 collector to emitter

voltage, dc with specified circuit between base and emitter and 5.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

Between 2.00 amperes source cutoff current and 5.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

100.0 watts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

# **Special Features:**

Junction pattern arrangement: npn

# **Terminal Type And Quantity:**

2 pin and 1 case

# Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

No

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